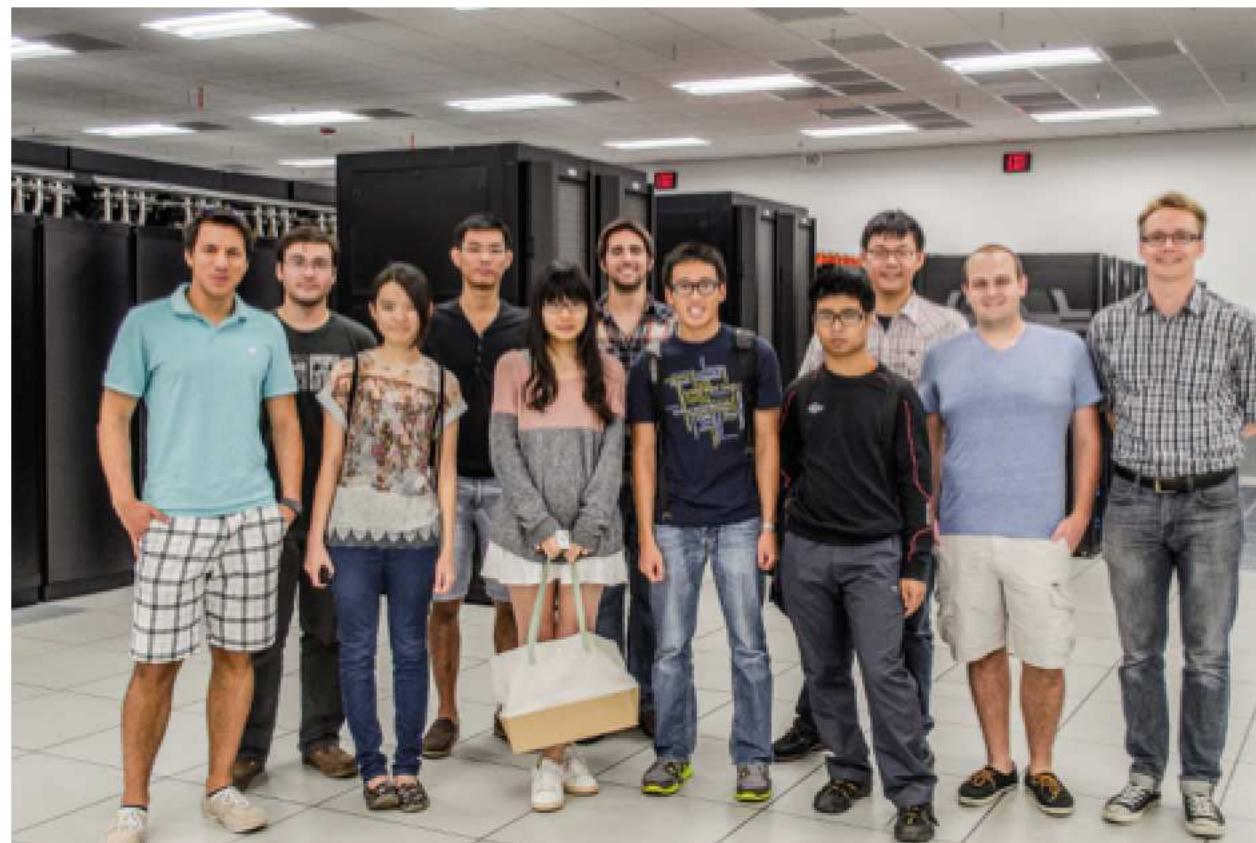


Optical Absorption Spectra of In_2O_3 and Ga_2O_3 from First-principles Calculations



Joel Varley, Condensed Matter and Materials Division, Lawrence
Livermore National Laboratory

André Schleife, Department of Materials Science and Engineering,
Univ. of Illinois at Urbana-Champaign



Blue Waters Symposium 2015: 5/11/2015, Sun River, OR

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Acknowledgments:

- Martin Feneberg
- Klaus Irmscher
- Anderson Janotti
- Chris G. Van de Walle



Applications of Oxide Semiconductors



Why it Matters:

Optoelectronics and semiconductor technology:

- Lasers and light-emitting diodes
- Transparent electronics

Plasmonics

Energy-related applications:

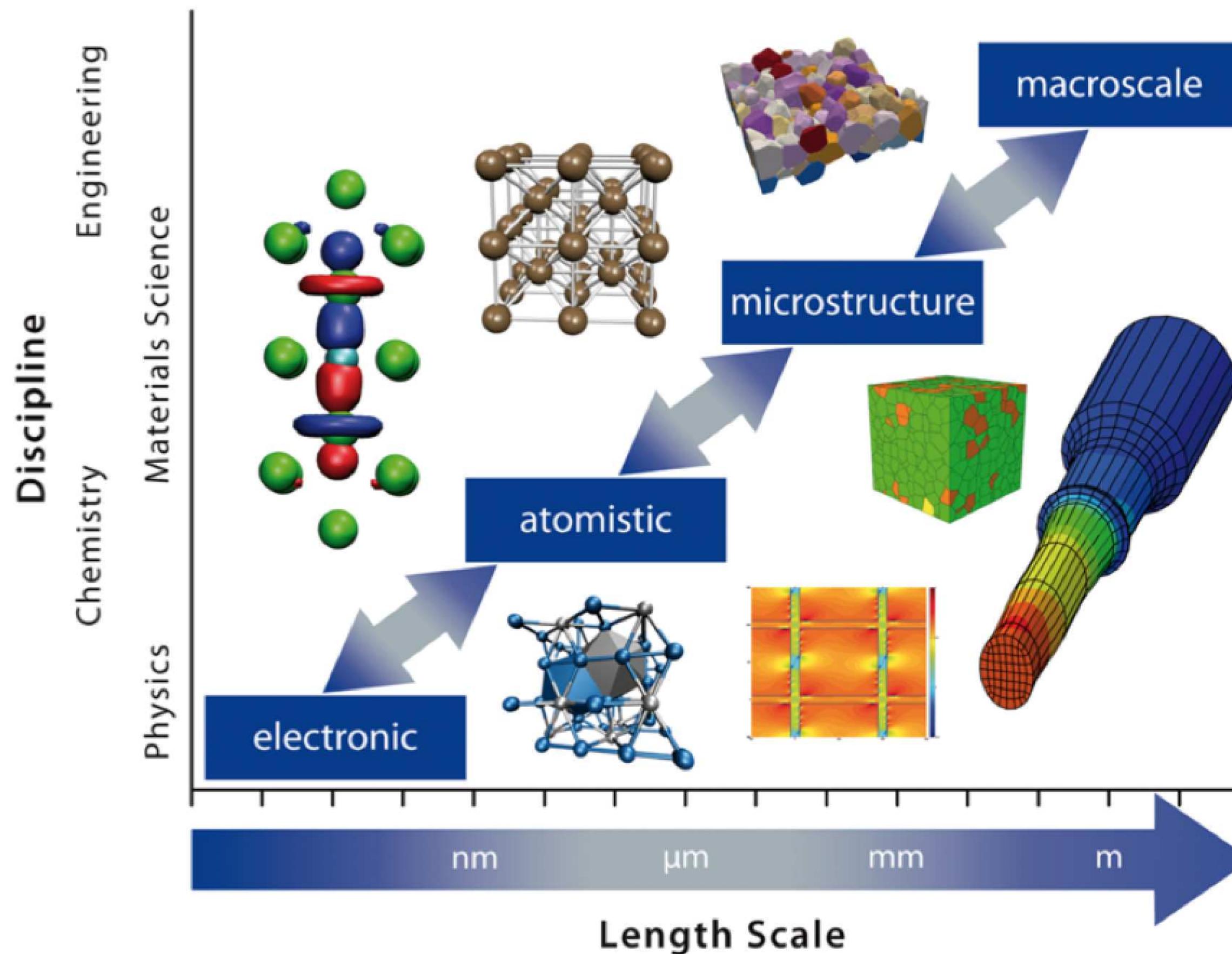
- Photocatalytic water splitting
- Transparent electrodes: Solar cells
- Piezoelectronics



Some fundamentals not well understood/Key Challenges:

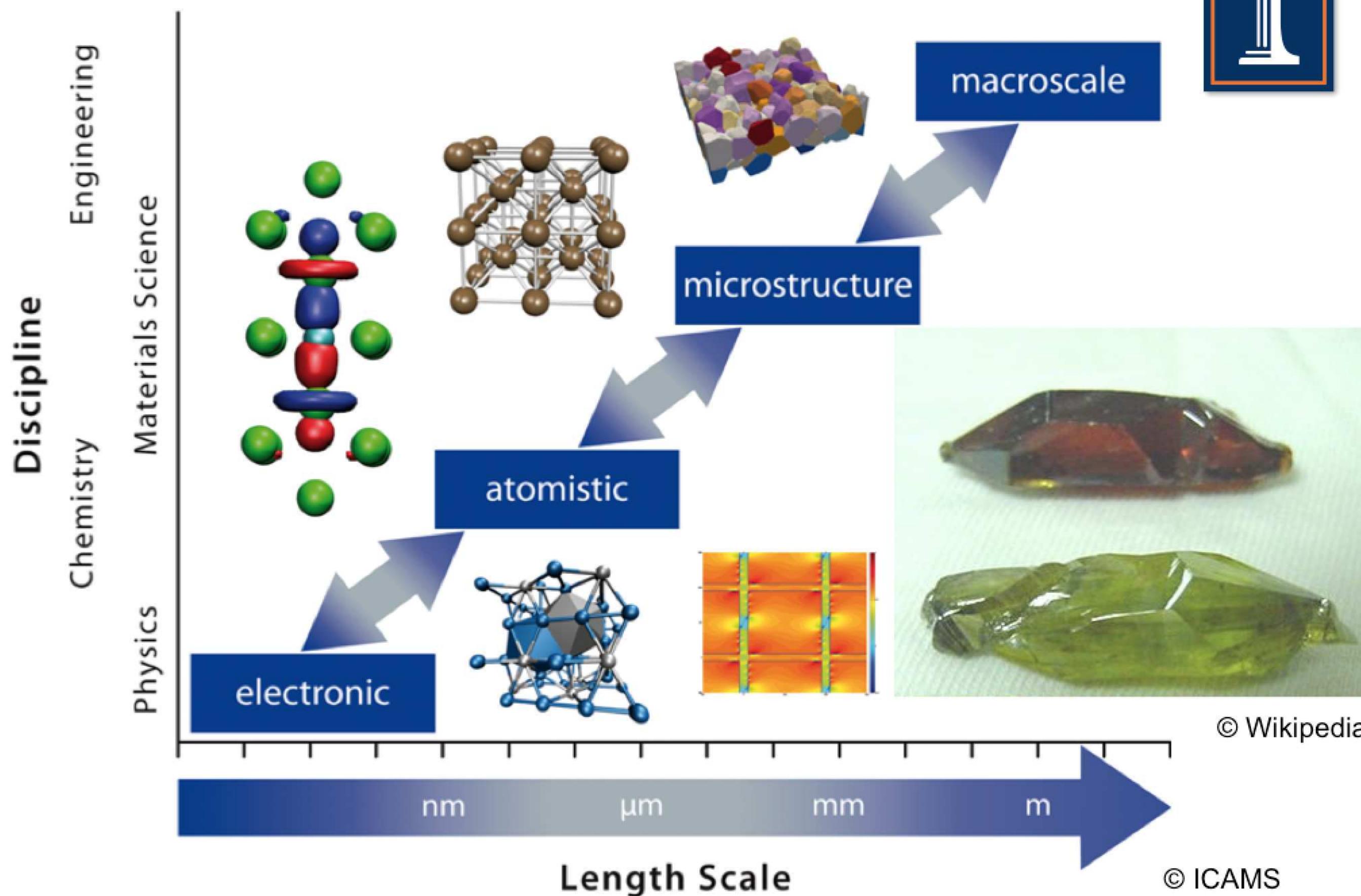
- Optical absorption?
- Excitonic effects?
- Anisotropy?
- Outlook: Understand influence of free electrons

Here: Atomistic Length (and Time) Scales

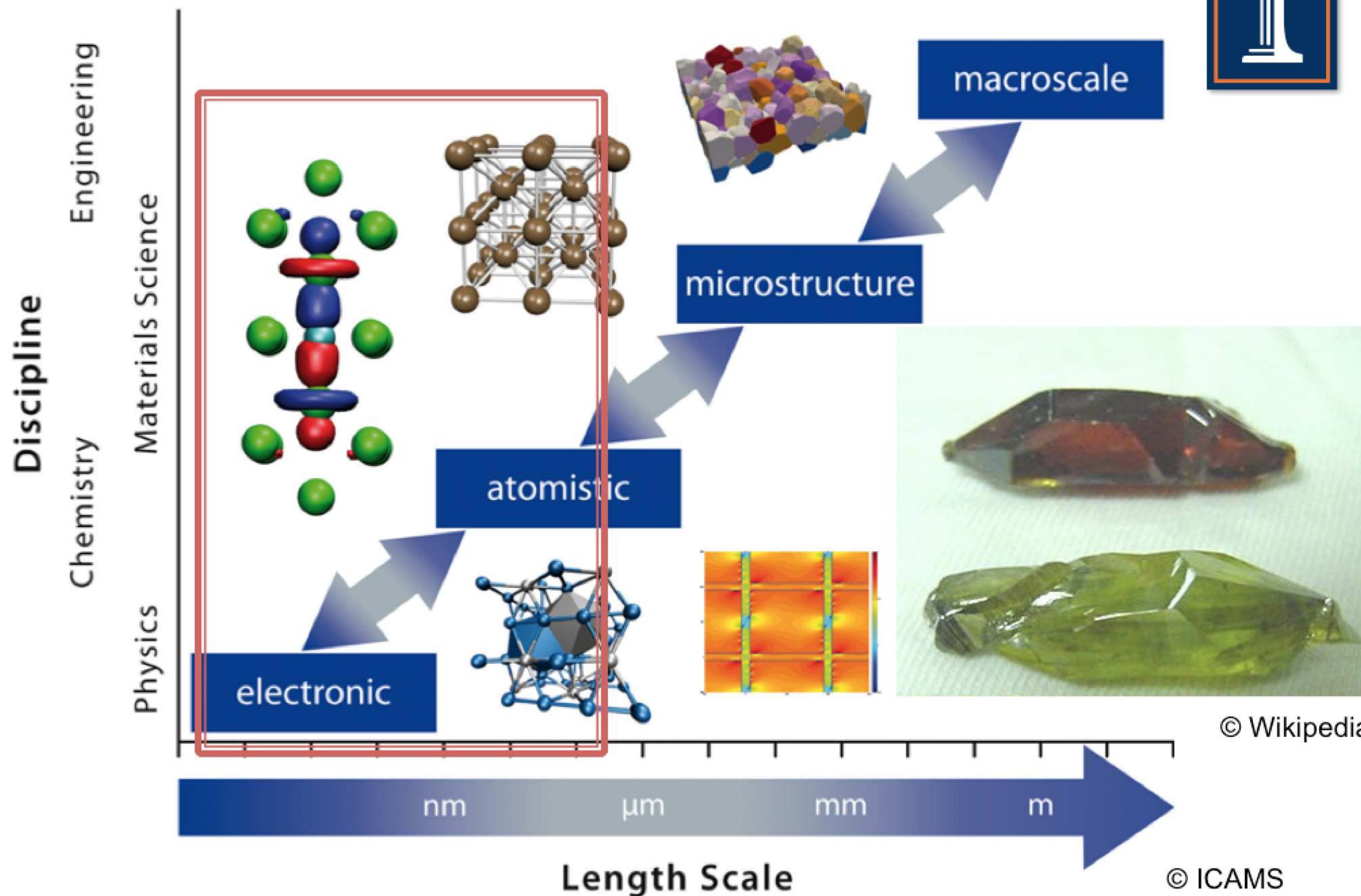


© ICAMS

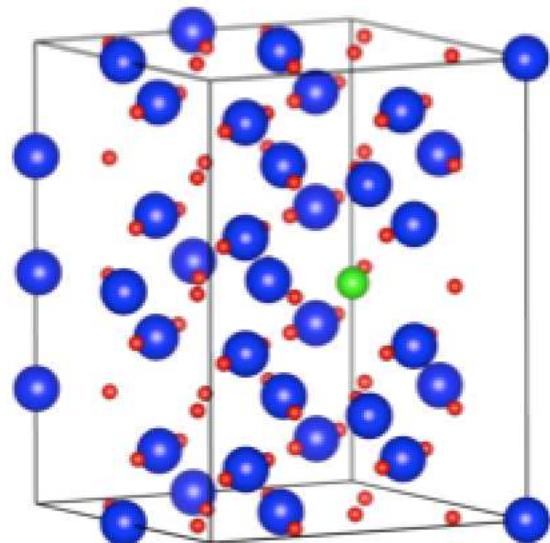
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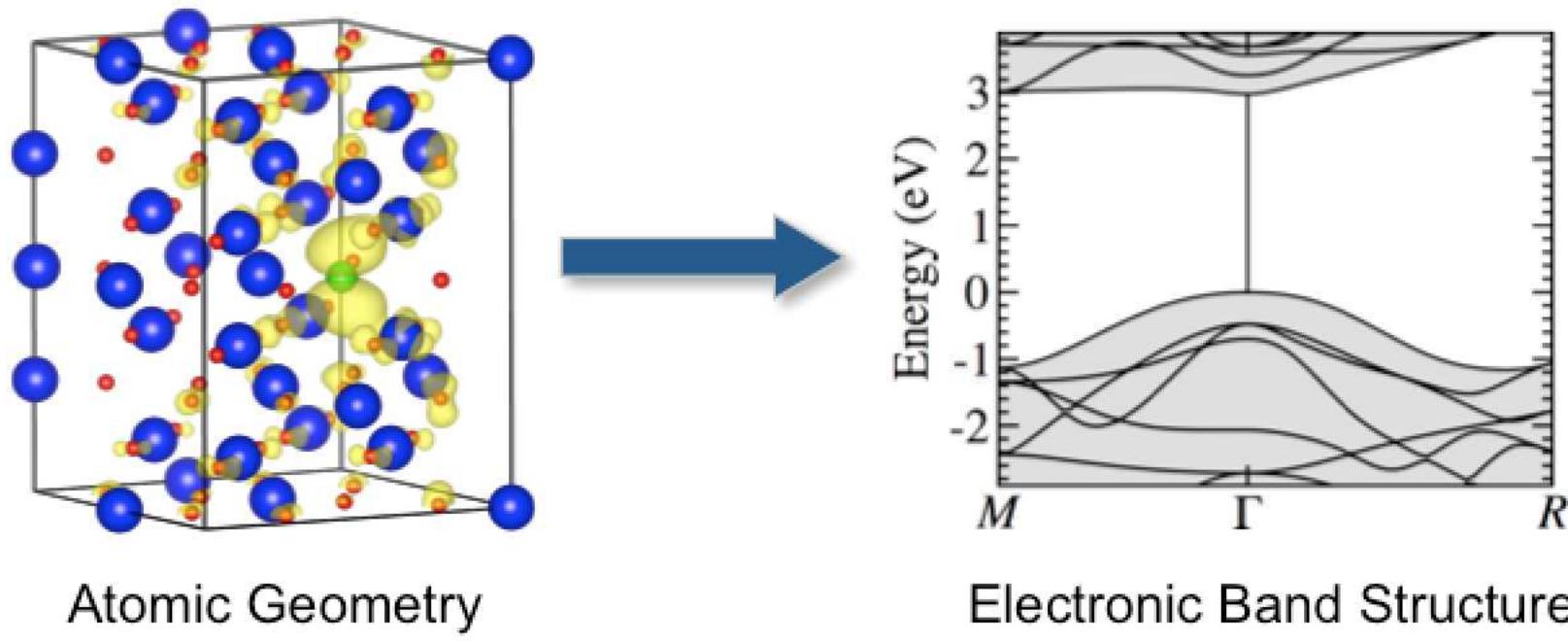


Optoelectronics from First-Principles Theory

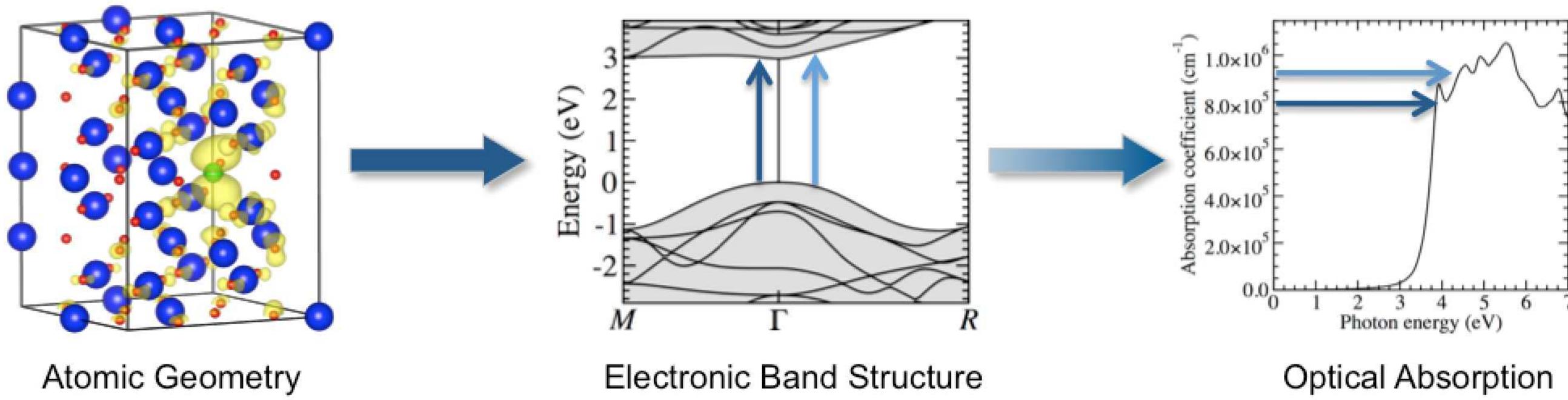


Atomic Geometry

Optoelectronics from First-Principles Theory



Optoelectronics from First-Principles Theory



Atomic Geometry

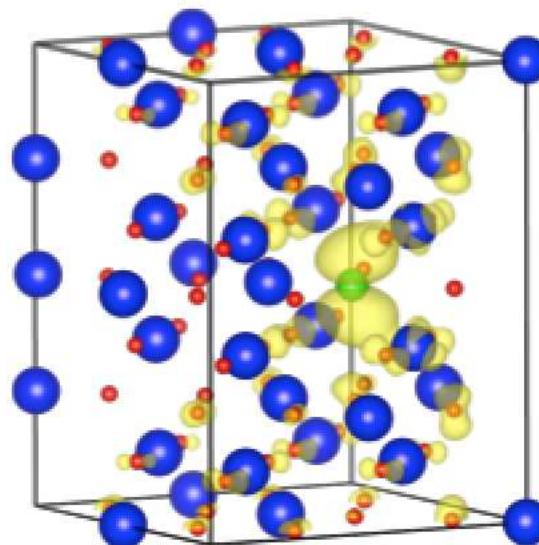
Electronic Band Structure

Optical Absorption

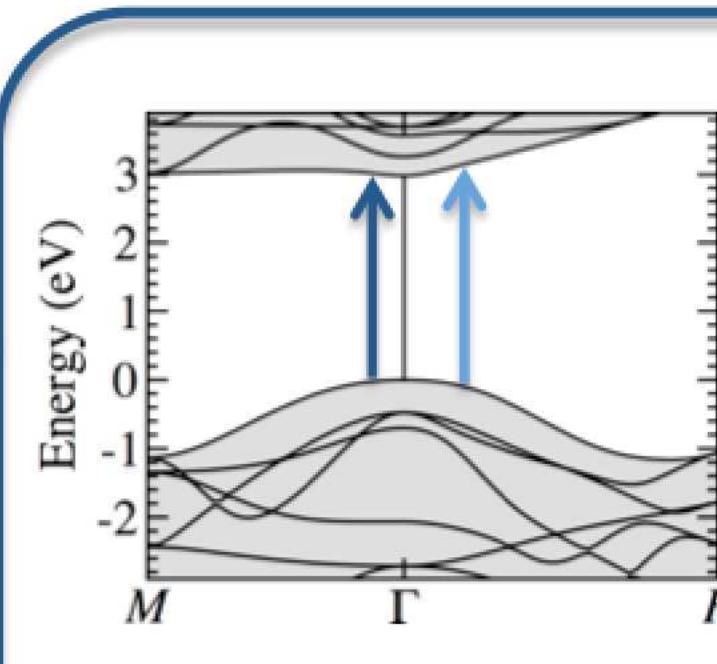
Optoelectronics from First-Principles Theory



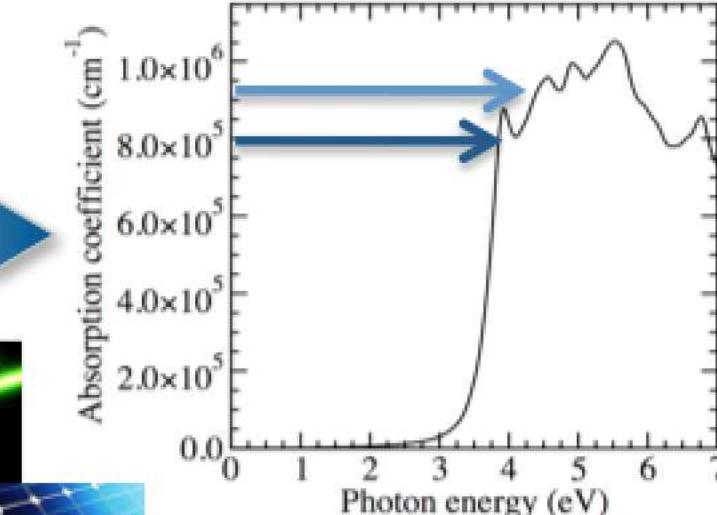
Excited electronic states



Atomic Geometry



Electronic Band Structure

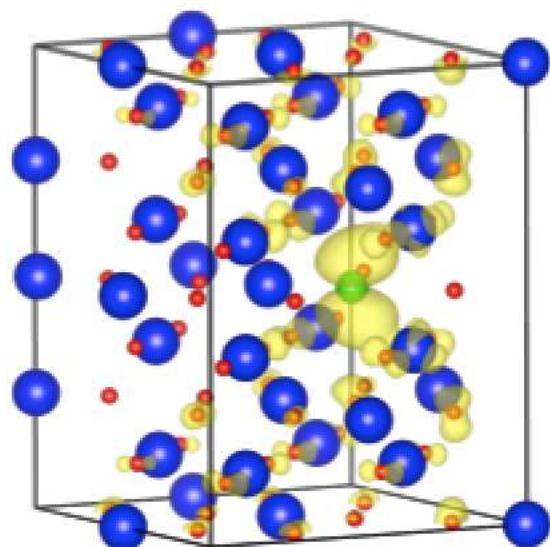


Optical Absorption

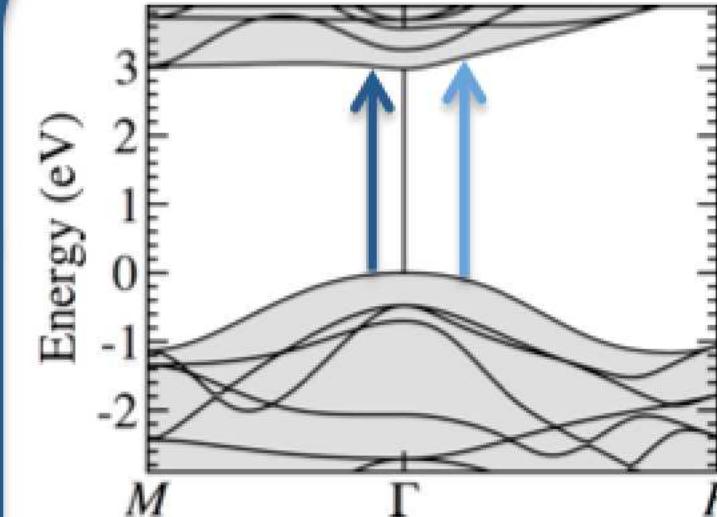
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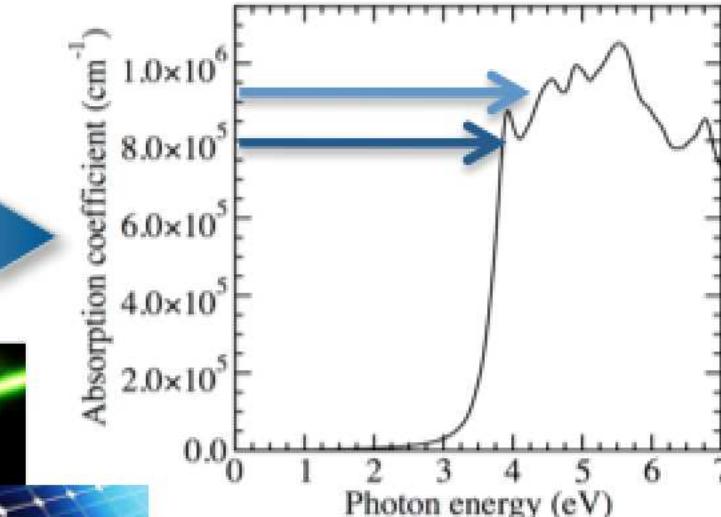
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Atomic Geometry



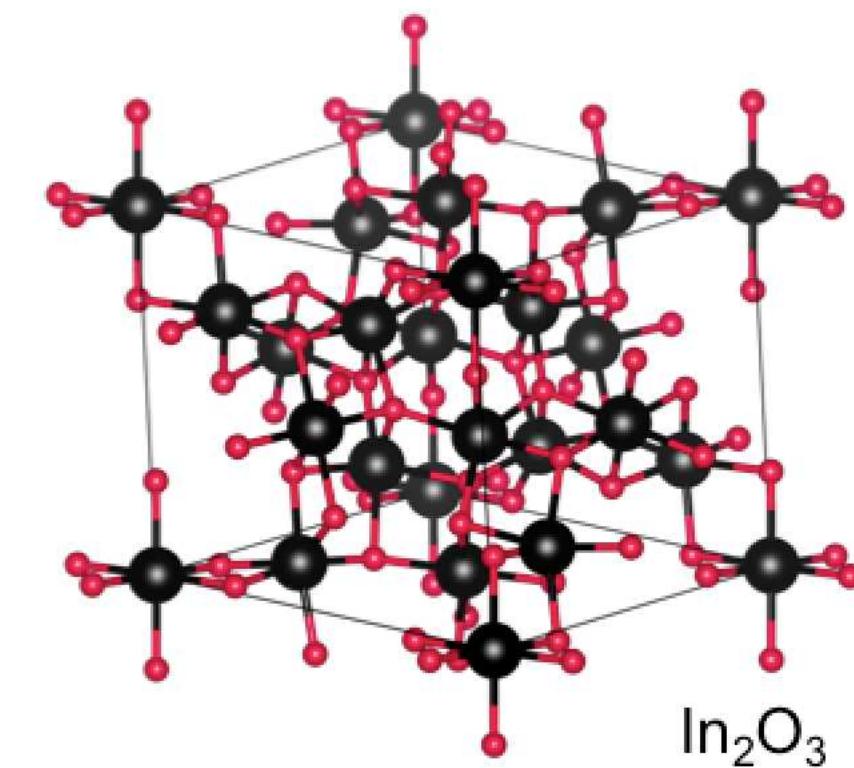
Electronic Band Structure



Optical Absorption

Problems/Key Challenges:

- Computationally expensive techniques
- Limitations of approximations used?
- Large unit cells to simulate
- Experiment: High-quality single crystals are rare

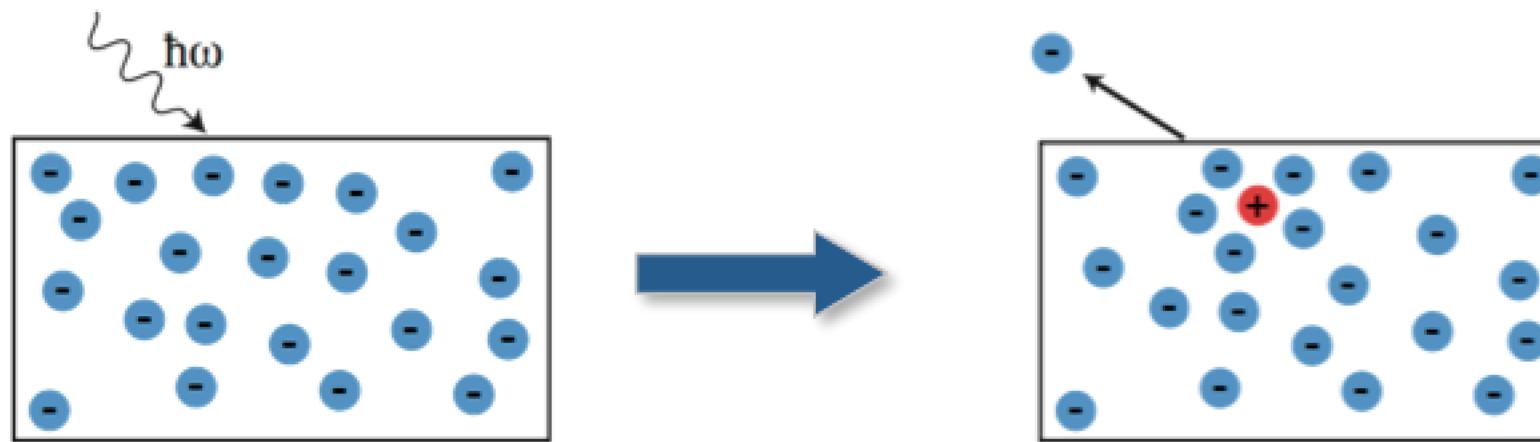


In₂O₃

Single-Particle Excitations: Background



Photoemission spectroscopy (PES)

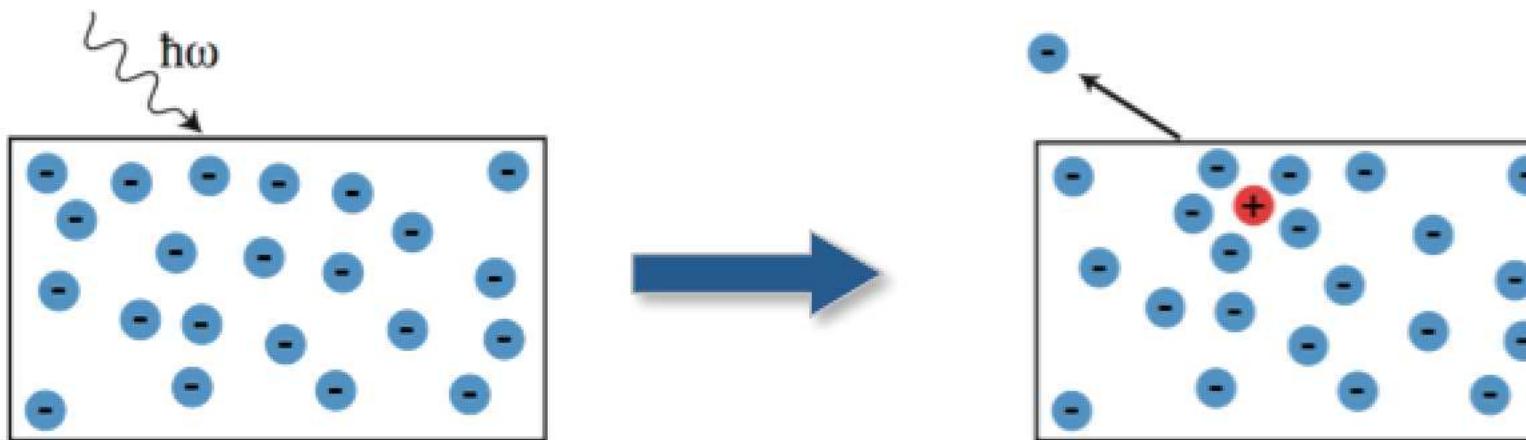


- Removal (PES) or addition (inverse PES) of an electron
- Important: Reaction of the electrons of the system

Single-Particle Excitations: Background



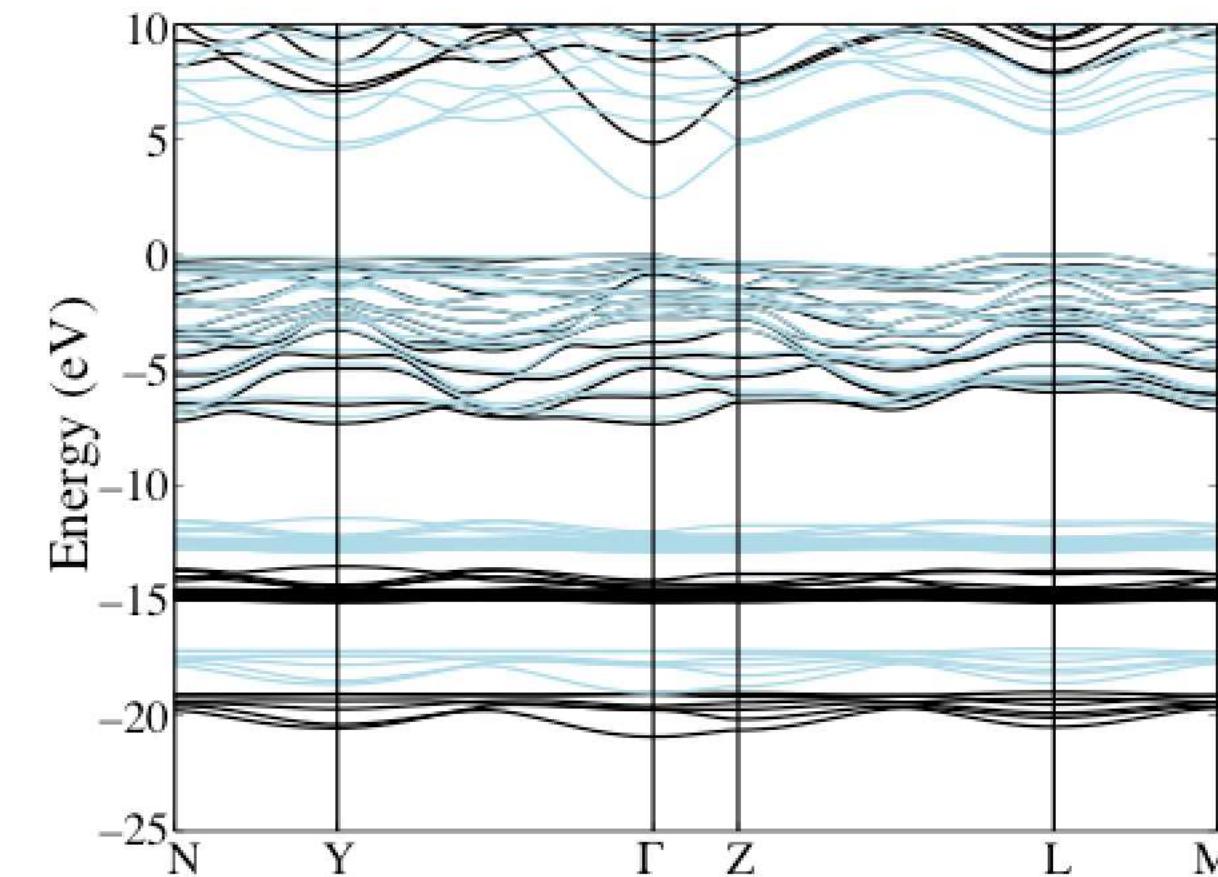
Photoemission spectroscopy (PES)



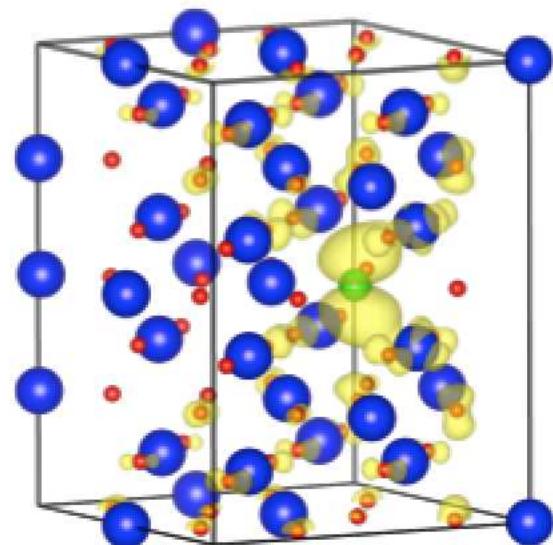
- Removal (PES) or addition (inverse PES) of an electron
- Important: Reaction of the electrons of the system

Example: beta-Ga₂O₃

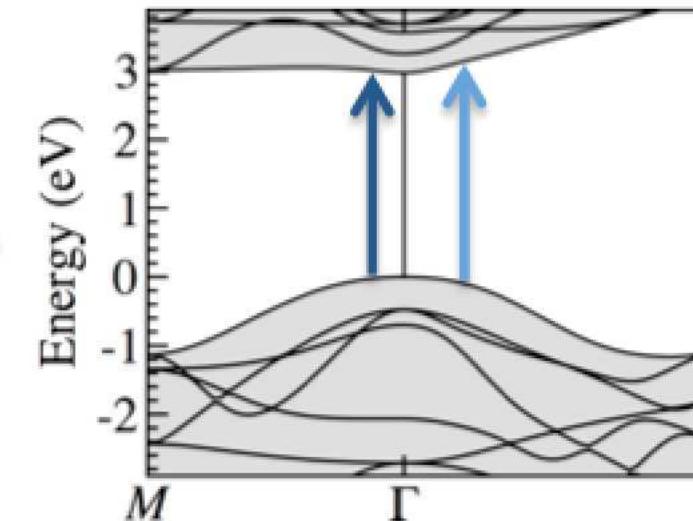
- DFT-PBE band gap too small: 2.5 eV
- HSE reproduces experiment well (4.86 eV)
- Here: PBE+ Δ
- Agrees well with HSE (valence band width: 7.07 eV vs. 7.33 eV, Exp: 7.37 eV)
- (small) Mismatch at higher energies



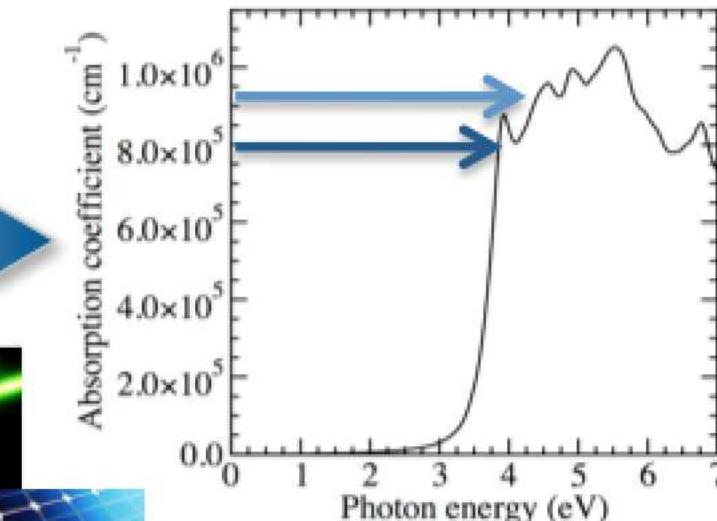
Optoelectronics from First-Principles Theory



Atomic Geometry



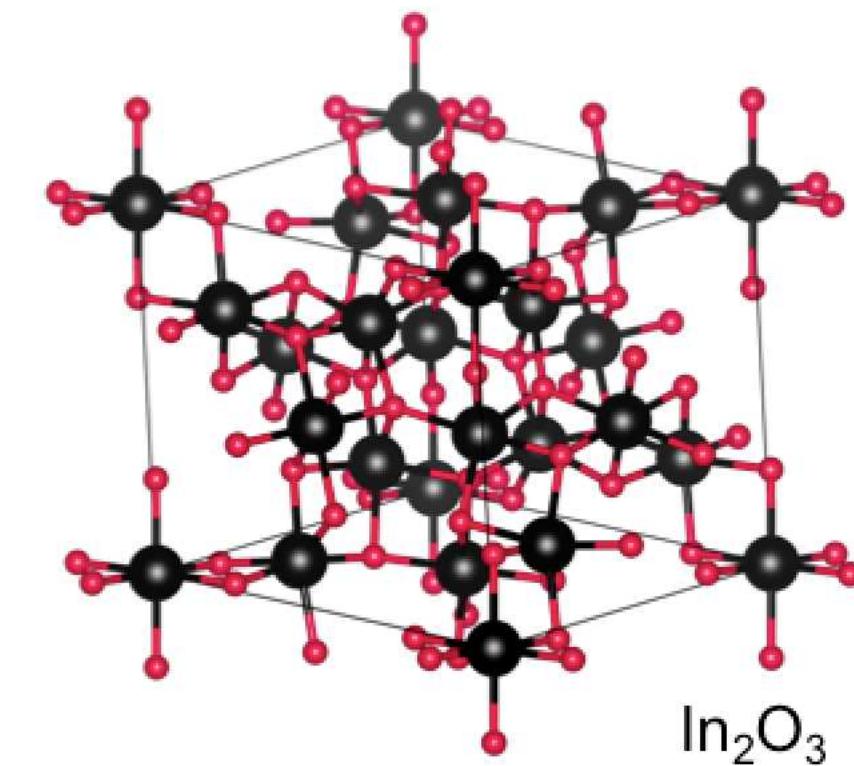
Electronic Band Structure



Optical Absorption

Problems/Key Challenges:

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- Limitations of approximations used?
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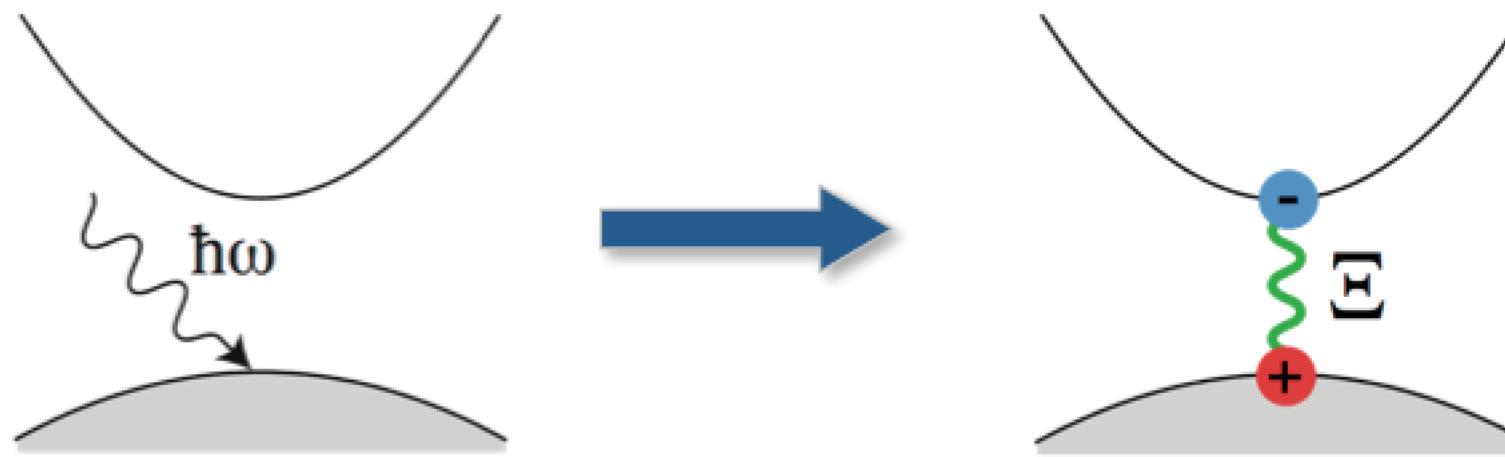


In₂O₃

Two-Particle Excitations: Background



Optical Absorption:

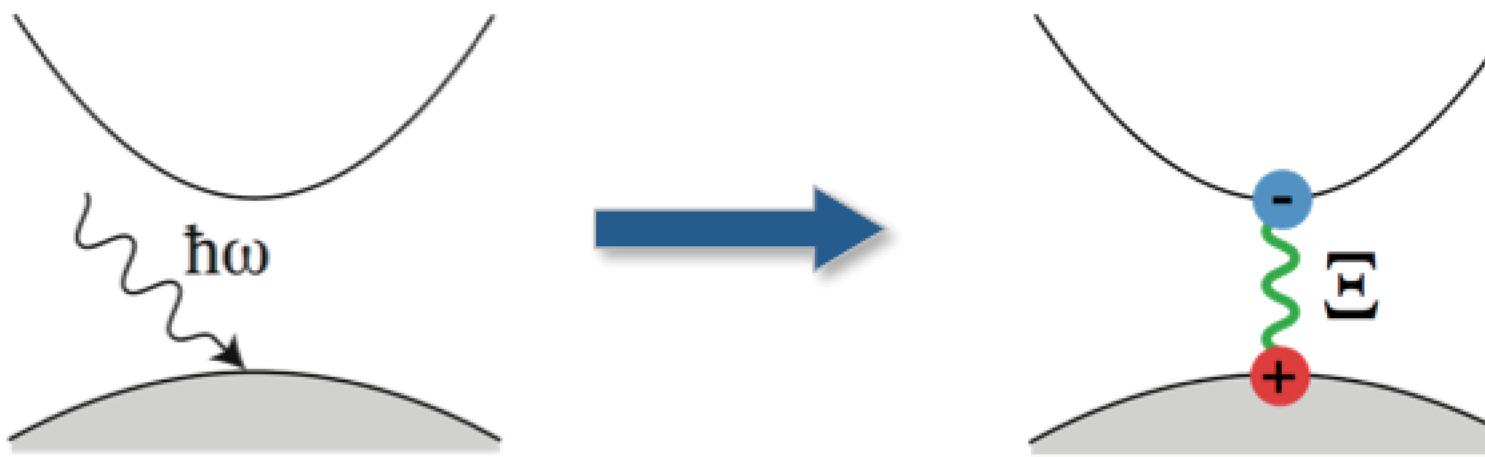


- Electron from valence band excited into conduction band
- Electron-hole attraction (screened Coulomb potential)
- Macroscopic dielectric function: Local-field effects

Two-Particle Excitations: Background



Optical Absorption:



- Electron from valence band excited into conduction band
 - Electron-hole attraction (screened Coulomb potential)
 - Macroscopic dielectric function: Local-field effects
- Bethe-Salpeter equation for optical polarization function
→ Electron-hole interaction: Ξ

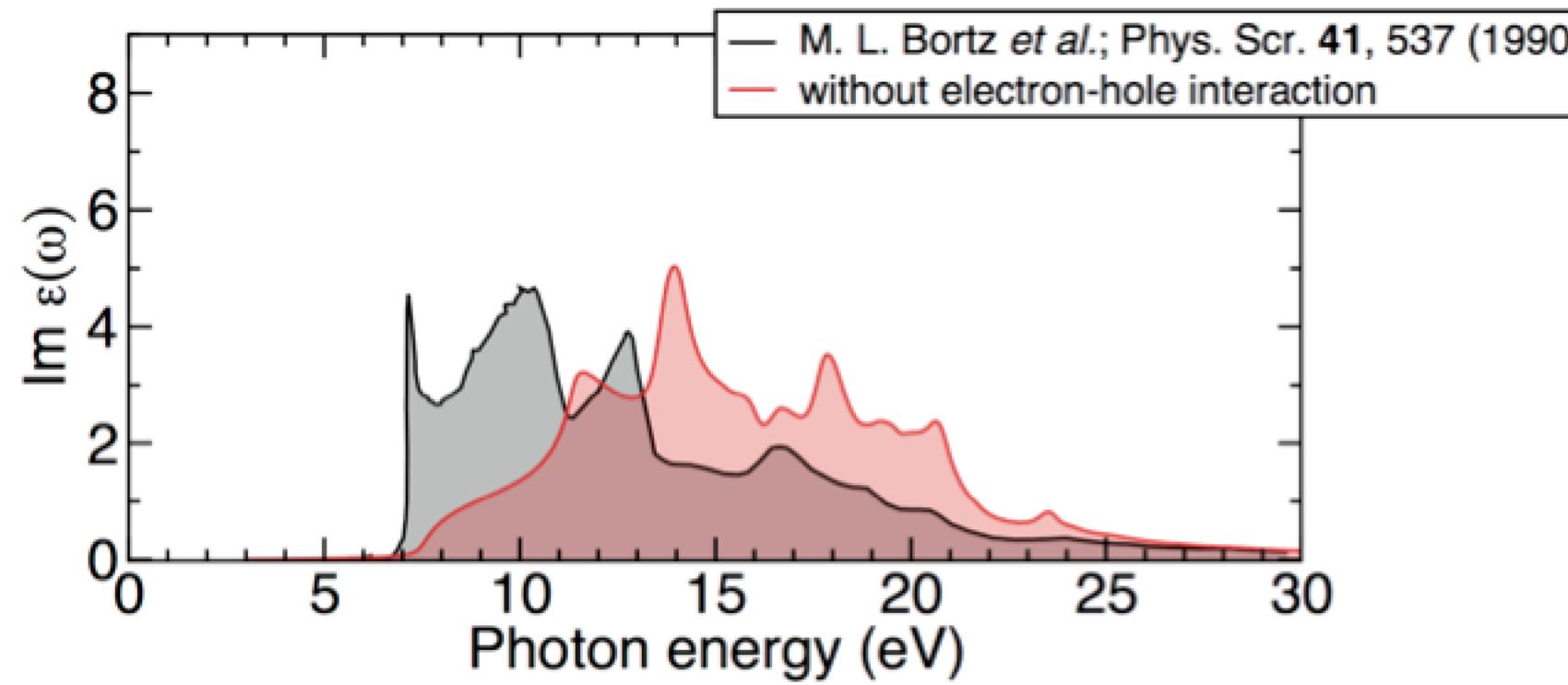
$$P(11', 22') = P_0(11', 22') + \iiint d3 d4 d5 d6 P_0(11', 43) \Xi(34, 65) P(56, 22')$$

$$\epsilon(11') = \delta(1 - 1') - \int d2 v(1 - 2) P(22^+, 1'1'^+) \quad 1 := \mathbf{r}_1, t_1$$

Why BSE? Why Blue Waters?



Example: MgO



F. Fuchs, A. Schleife *et al.*; Phys. Rev. B **78**, 085103 (2008)

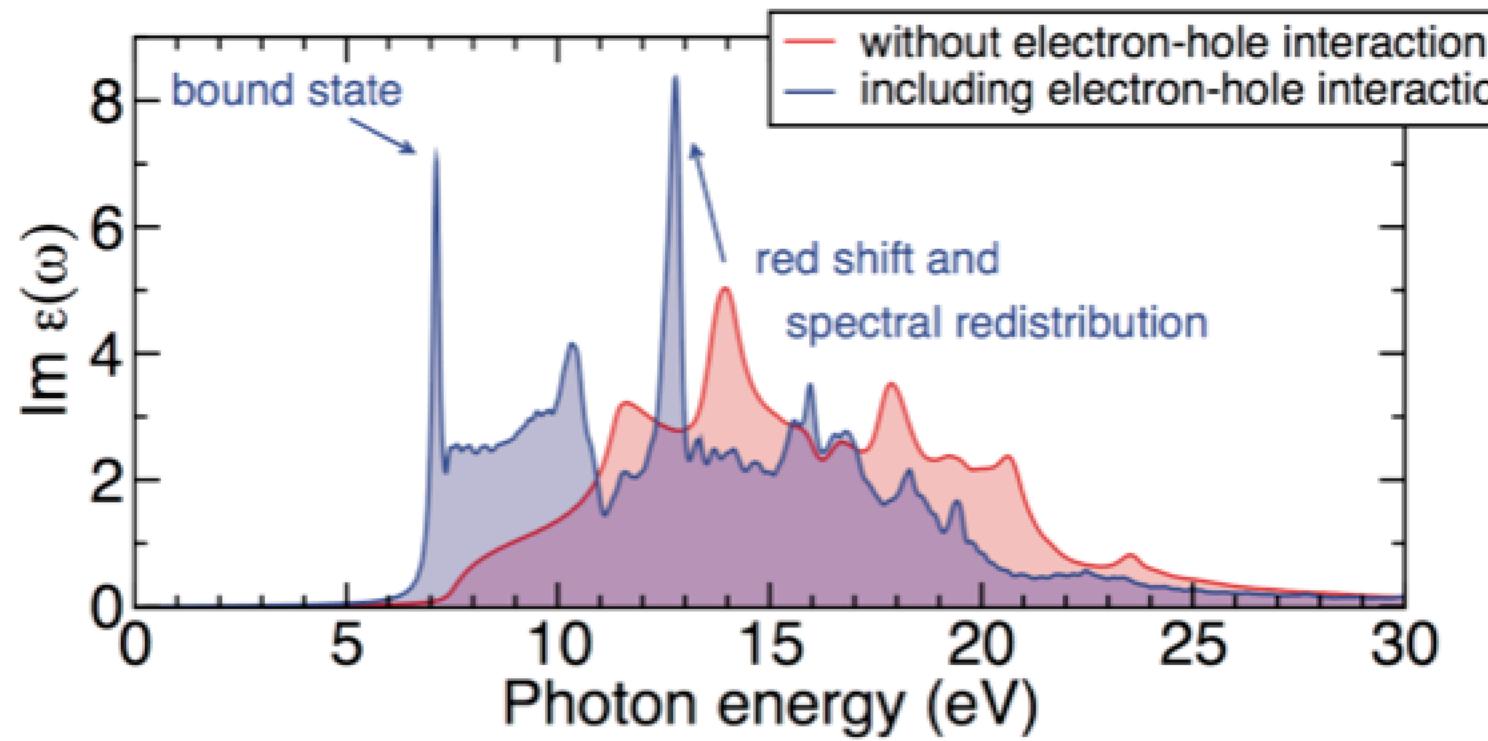
A. Schleife *et al.*; Phys. Rev. B **80**, 035112 (2009)

J. Varley and A. Schleife; Semicond. Sci. Tech. **30**, 024010 (2015)

Why BSE? Why Blue Waters?



Example: MgO



Excitonic effects: Solution of the Bethe-Salpeter equation

- Leads to eigenvalue problem ("excitonic Hamiltonian")
- Huge matrix: Rank > 50k (MgO)
- Time-propagation approach to calculate the dielectric function

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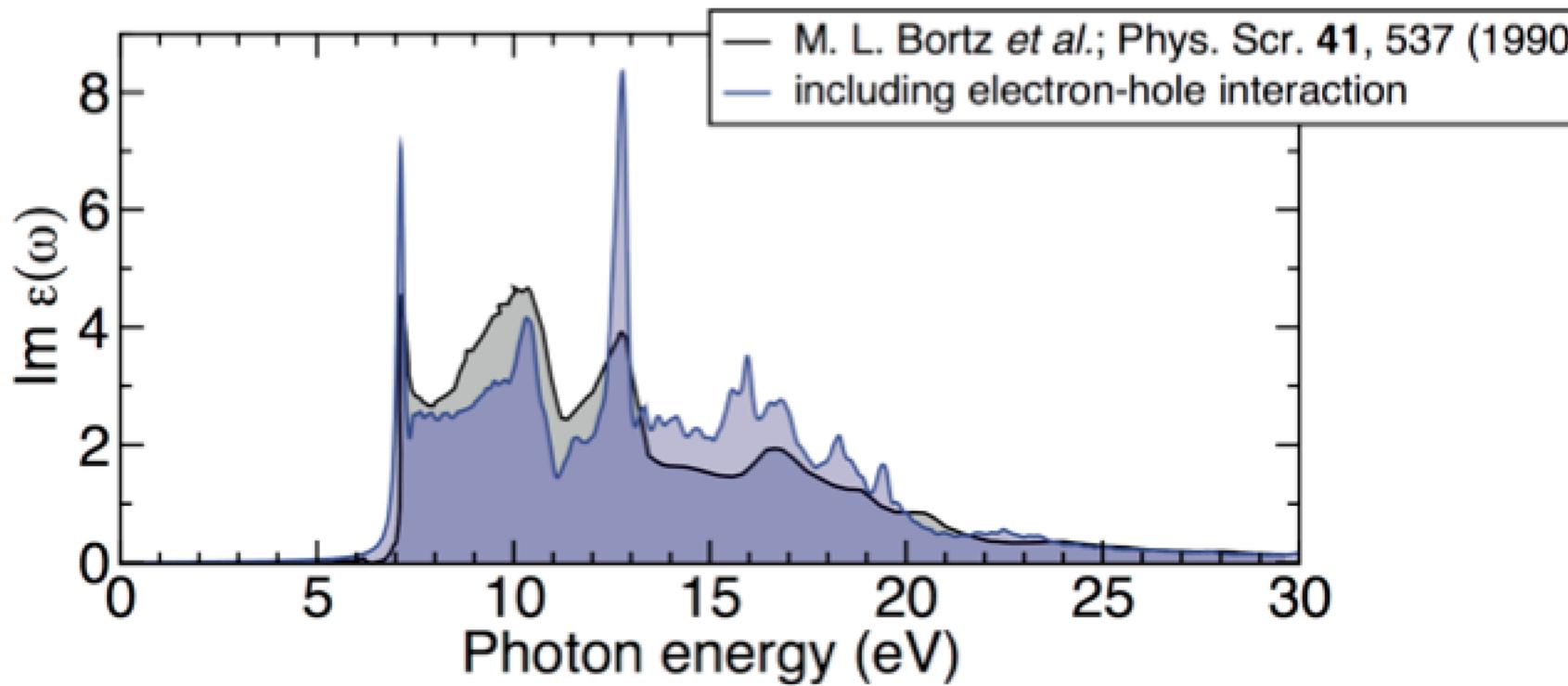
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Why BSE? Why Blue Waters?



Example: MgO



Excitonic effects: Solution of the Bethe-Salpeter equation

- Leads to eigenvalue problem ("excitonic Hamiltonian")
 - Huge matrix: Rank > 50k (MgO)
 - Time-propagation approach to calculate the dielectric function
 - Excellent description of the optical properties of the oxides
- Predictive power (e.g. for In_2O_3 , Ga_2O_3 , ...)

F. Fuchs, A. Schleife *et al.*; Phys. Rev. B **78**, 085103 (2008)

A. Schleife *et al.*; Phys. Rev. B **80**, 035112 (2009)

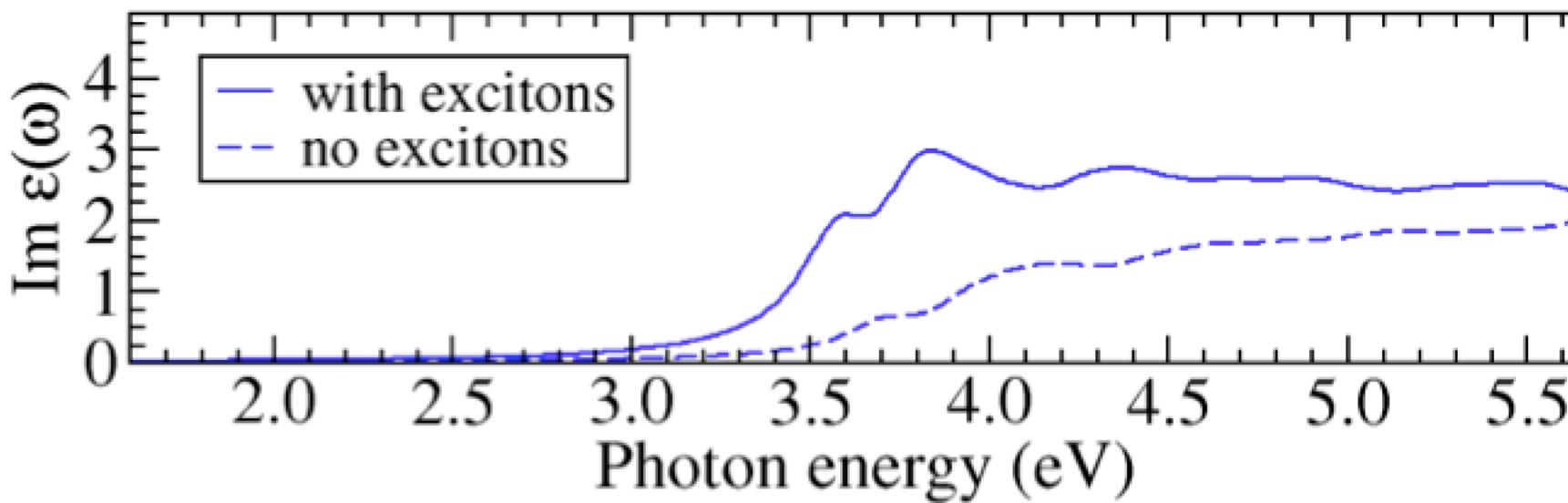
J. Varley and A. Schleife; Semicond. Sci. Tech. **30**, 024010 (2015)

Results: Excitons in cubic In_2O_3



Accomplishments:

DFT vs. BSE near band edge:



- Slight red shift of absorption edge: Exciton binding energy
- Sampling of Brillouin zone is biggest computational challenge
- Shape of onset strongly affected: Bound excitonic state
- Cubic material: No anisotropy of the dielectric function
- Description of screening??

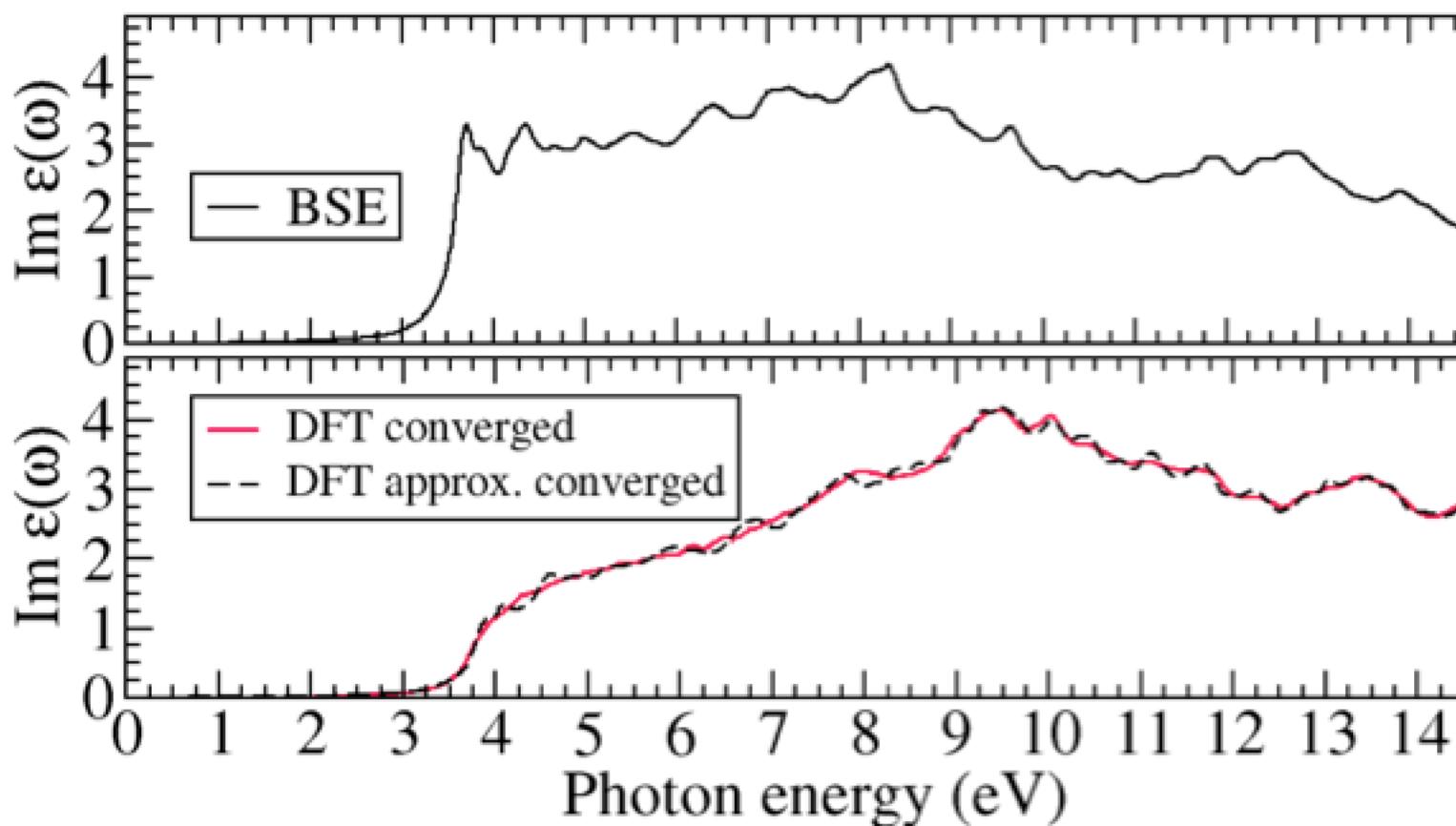
J. Varley and A. Schleife; Semicond. Sci. Tech. **30**, 024010 (2015)

Results: Excitons in cubic In_2O_3



Accomplishments:

DFT and BSE: Large photon energy range



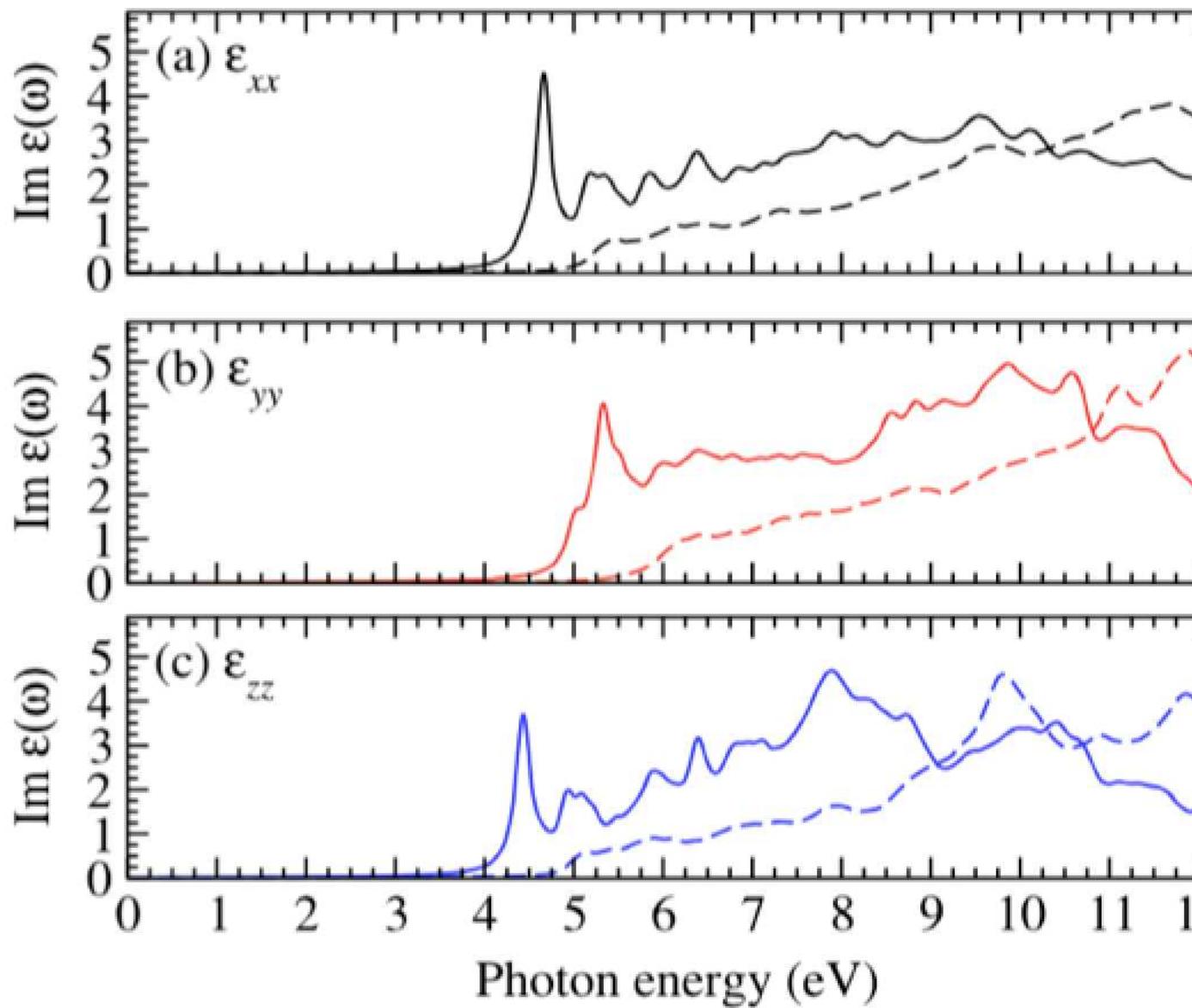
- Pronounced difference across entire energy range
- DFT peaks tend to be red-shifted in BSE
- Computationally challenging: Matrix ranks reach 360k (In_2O_3) – i.e. up to about 1 TB
- Influence of screening?
- Influence of quasiparticle corrections? J. Varley and A. Schleife; Semicond. Sci. Tech. **30**, 024010 (2015)

Two-Particle Excitations: monoclinic Ga_2O_3



Accomplishments:

Optical spectrum across large photon energy range:



- Screening smaller than in In_2O_3 ($\epsilon_0=4.05$ vs. 4.80):
Excitonic effects more pronounced
- Strong excitonic bound state dominates onset
- Very strong optical anisotropy
- Excitonic effects do not affect anisotropy significantly

J. Varley and A. Schleife; Semicond. Sci. Tech. **30**, 024010 (2015)

Summary and Outlook



Summary

- Study of optical properties of complex, technologically relevant materials
- Impact: High (predictive) accuracy for computational materials design,
Develop understanding of exciton physics
- Computationally expensive and approximations are involved
- Blue Waters extremely useful in order to tackle high memory/data throughput requirements
- Accurate results over large photon energy range
- Strong influence of excitonic effects and anisotropy

J. Varley and A. Schleife; Semicond. Sci. Tech. **30**, 024010 (2015)

Outlook

- Code that can explore:
 - Influence of free carriers (e.g. for plasmonics)
 - Influence of screening due to electron-phonon coupling
 - Multiple length scales